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## IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

ATTY.'S DOCKET: 98 P7501 US 01

In re the application of: Ramachandran et al.

Group Art: 1746

Serial No.: 09/204,706

Examiner: A. Olsen

Filing Date: December 3, 1998

elling Date: December 3, 1996

Title: REMOVAL OF POST-RIE POLYMER)

ON Al/Cu METAL LINE

## AMENDMENT UNDER 37 C.F.R. §1.115

Honorable Commissioner of Patents and Trademarks Washington, D.C. 20231

Sir:

In reply to the Office Action mailed March 28, 2002, which rejected the claims in the above-identified patent application, applicants respectfully request reconsideration, based upon the amendments hereinafter set forth.

## IN THE CLAIMS:

- 13. (4th Amended) In a metal etch tool for removing post-RIE polymer rails formed on a Al/Cu metal line of a semiconductor structure, the improvement comprising:
- I an integrated metal etch tool <u>interfaceable with</u>
  [comprising therein];
- a) strip chamber means for water only plasma to strip photo-resist of a semiconductor composite structure subsequent to a RIE to limit thickness of sidewall polymer <u>rails</u>;
  - b) vacuum chamber means to chemically modify <u>sidewall</u>

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